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**ON Semiconductor®** 

# FDPC4044 Common Drain N-Channel PowerTrench<sup>®</sup> MOSFET

## **30 V, 27 A, 4.3 m**Ω

### Features

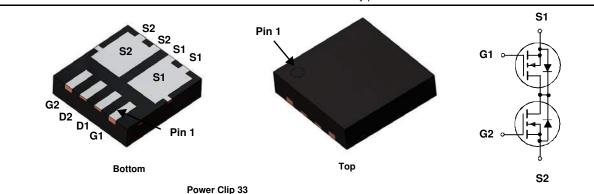
- Max  $r_{S1S2(on)}$  = 4.3 m $\Omega$  at  $V_{GS}$  = 10 V,  $I_{S1S2}$  = 27 A
- Max  $r_{S1S2(on)}$  = 6.4 m $\Omega$  at  $V_{GS}$  = 4.5 V,  $I_{S1S2}$  = 23 A
- Pakage size/height: 3.3 x 3.3 x 0.8 mm
- Low inductance packaging shortens rise/fall times, resulting in lower switching losses
- MOSFET integration enables optimum layout for lower circuit inductance and reduced switch node ringing
- RoHS Compliant

# **General Description**

This device is designed specifically as a single package solution for Li-lon battery pack protection circuit and other ultra-portable applications. It features two common drain N-channel MOSFETs, which enables bidirectional current flow. FDPC4044 combines ON Semiconductor's advanced PowerTrench<sup>®</sup> process with state of the art packaging process to minimize the on-state resistance.

### Applications

- Battery management
- Load switch
- Battery protection



### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V <sub>S1S2</sub>	Source1 to Source2 Voltage			30	V
V <sub>GS</sub>	Gate to Source Voltage		(Note 3)	±20	V
I <sub>S1S2</sub>	Source1 to Source2 Current -Continuous T <sub>A</sub>	<sub>A</sub> = 25 °C	(Note 1a)	27	^
	-Pulsed (Not		(Note 2)	120	Α
P <sub>D</sub>	Power Dissipation T <sub>A</sub>	_= 25 °C	(Note 1a)	2.7	w
	Power Dissipation T <sub>A</sub>	, = 25 °C	(Note 1b)	1	vv
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to +150	°C

### **Thermal Characteristics**

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	47	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	127	C/ VV

### Package Marking and Ordering Information

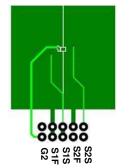
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
40CF	FDPC4044	Power Clip 33	13 "	12 mm	3000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
I <sub>S1S2</sub>	Zero Gate Voltage Source1 to Source2 Current	V <sub>S1S2</sub> = 24 V, V <sub>GS</sub> = 0 V			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = 20 V, V <sub>S1S2</sub> = 0 V			100	nA
On Chara	cteristics					
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>S1S2</sub> , I <sub>S1S2</sub> = 250 μA	1.2	1.5	3	V
	Static Source1 to Source2 On Resistance	V <sub>GS</sub> =10 V, I <sub>S1S2</sub> = 27 A		3.2	4.3	
r <sub>S1S2(on)</sub>		V <sub>GS</sub> = 4.5 V, I <sub>S1S2</sub> = 23 A			6.4	mΩ
		$V_{GS} = 10 \text{ V}, I_{S1S2} = 27 \text{ A},$ T <sub>J</sub> = 125 °C		4.5	7	- 11152
9fs	Forward Transconductance	V <sub>S1S2</sub> = 10 V, I <sub>S1S2</sub> = 27 A		150		S
Dynamic	Characteristics					
C <sub>iss</sub>	Input Capacitance			2295	3215	pF
C <sub>oss</sub>	Output Capacitance	V <sub>S1S2</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		627	880	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			66	95	pF
Switching	g Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			8.5	17	ns
t <sub>r</sub>	Rise Time	V <sub>S1S2</sub> = 15 V, I <sub>S1S2</sub> = 27 A, V <sub>GS</sub> = 10 V, R <sub>GEN</sub> = 6 Ω		4.8	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time			32	52	ns
t <sub>f</sub>	Fall Time	1		5.2	10	ns
Qg	Total Gate Charge			35	49	nC
Q <sub>gs</sub>	Gate to Source1 Gate Charge	V <sub>S1S2</sub> = 15 V, I <sub>S1S2</sub> = 27 A, V <sub>G1S1</sub> = 10 V, V <sub>G2S2</sub> = 0 V		5.7		nC

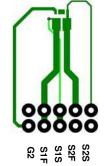
### Source1 to Source2 Diode Characteristics

I <sub>fss</sub>	Maximum Continuous Source1 to Source2 Diode Forward Current				1	А
Ve	Source1 to Source2 Diode Forward Voltage	$V_{G1S1} = 0 V, V_{G2S2}$ $I_{fss} = 27 A$	= 4.5 V, (Note 2)	0.8	1.2	V

Notes:
1. R<sub>6JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>6JC</sub> is guaranteed by design while R<sub>6CA</sub> is determined by the user's board design.



a. 47 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper.



b.127 °C/W when mounted on a minimum pad of 2 oz copper.

2. Pulse Test: Pulse Width < 300 us, Duty cycle < 2.0%.

3. As an N-ch device, the negative Vgs rating is for low duty cycle pulse ocurrence only. No continuous rating is implied.

1.5

V<sub>GS</sub> = 4.5 V

80

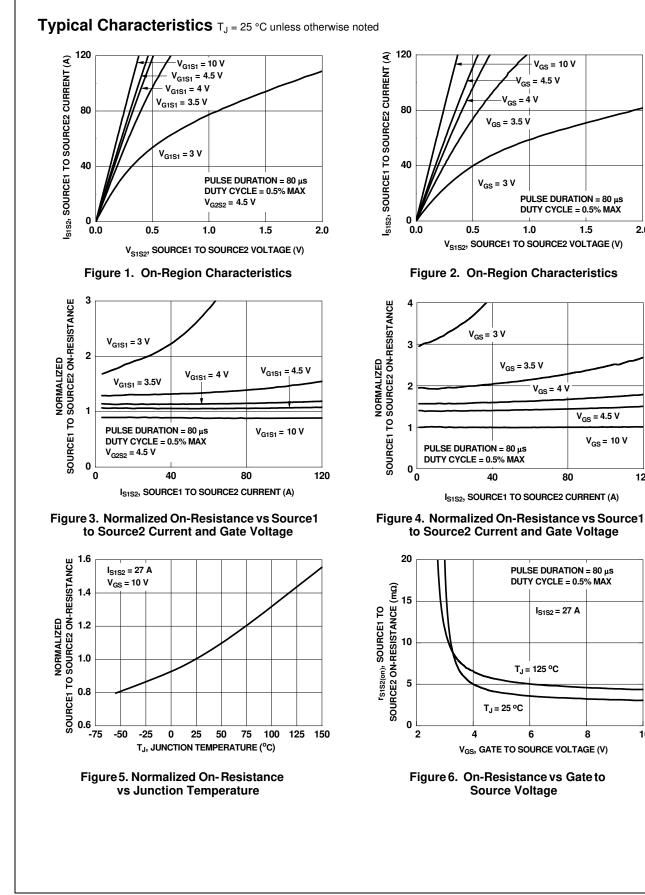
 $V_{GS} = 10 V$ 

120

10

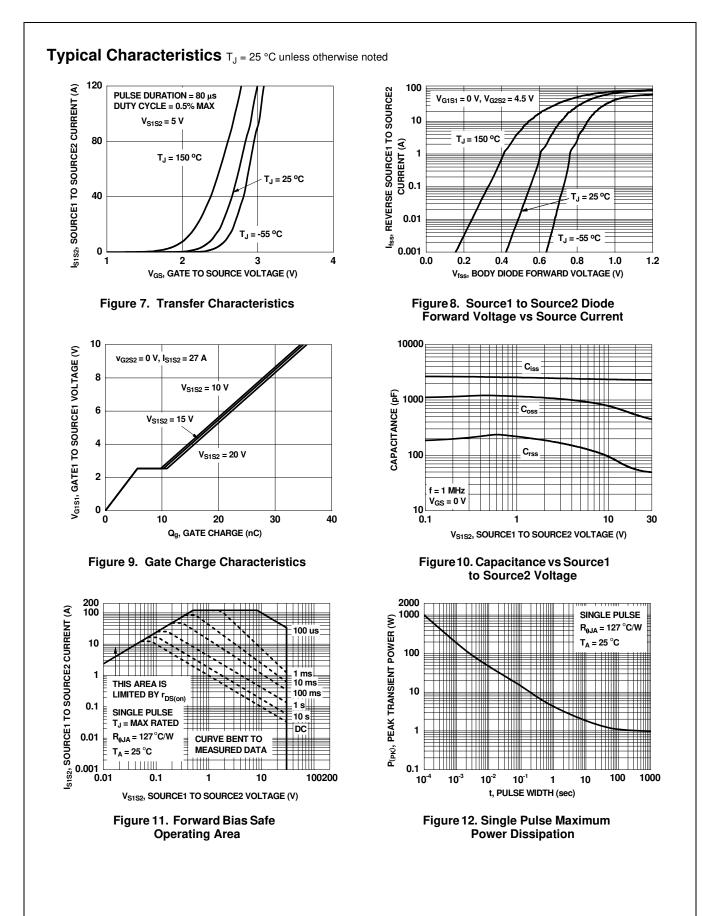
8

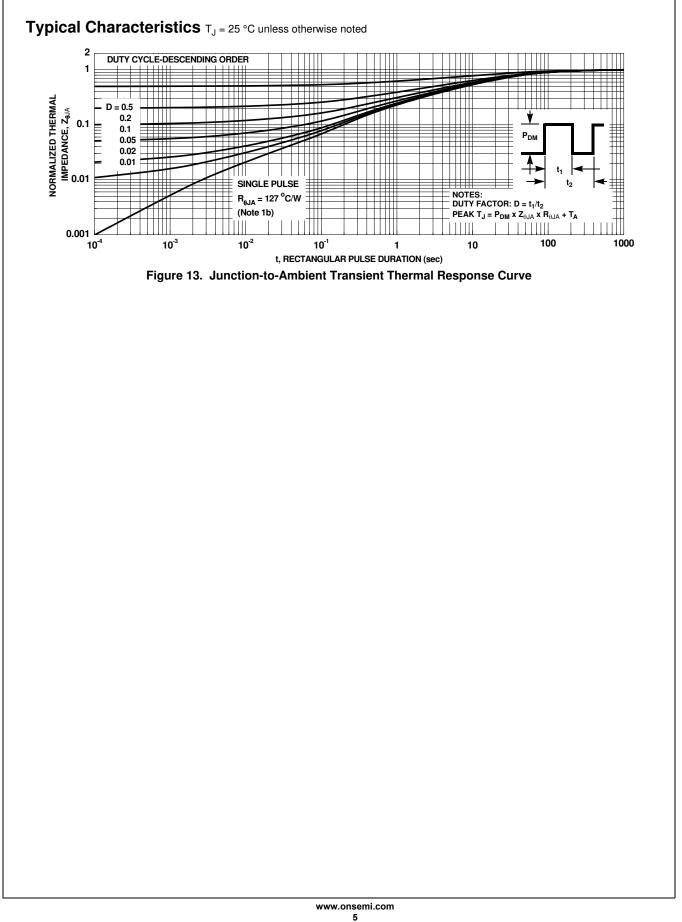
2.0

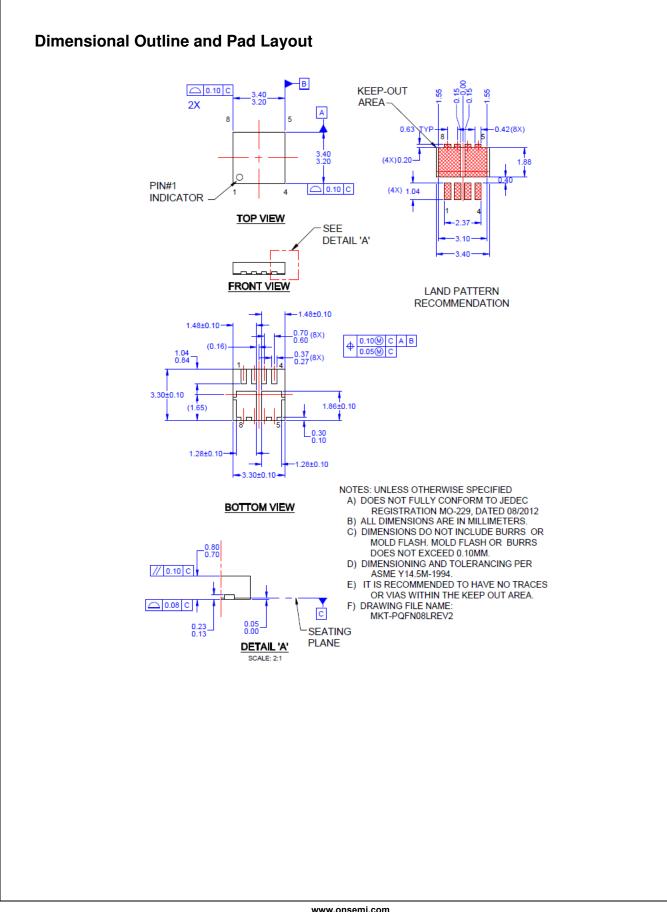


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